## NCE N-Channel Enhancement Mode Power MOSFET

#### **DESCRIPTION**

The NCE0224K uses advanced trench technology and design to provide excellent  $R_{DS(ON)}$  with low gate charge. It can be used in a wide variety of applications.

#### **GENERAL FEATURES**

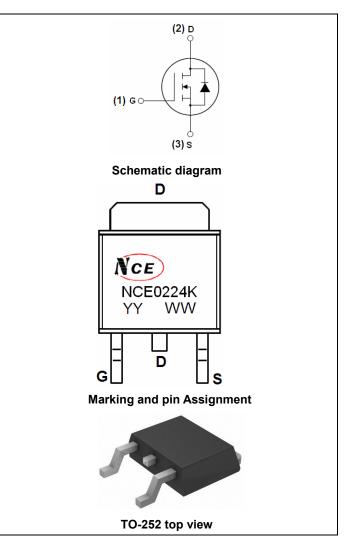
- $V_{DS}$  =200V, $I_{D}$  =24A  $R_{DS(ON)}$  < 80mΩ @  $V_{GS}$ =10V (Typ:63mΩ)
- High density cell design for ultra low Rdson
- Fully characterized Avalanche voltage and current
- Good stability and uniformity with high E<sub>AS</sub>
- Excellent package for good heat dissipation
- Special process technology for high ESD capability

#### **Application**

- Power switching application
- Hard Switched and High Frequency Circuits
- Uninterruptible Power Supply

100% UIS TESTED!

100% ΔVds TESTED!



#### **Package Marking And Ordering Information**

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE0224K	NCE0224K	TO-252	-	-	-

#### Absolute Maximum Ratings (TA=25 ℃unless otherwise noted)

	Parameter Symbol Limit U					
Parameter	Зуньы	LIIIII	Unit			
Drain-Source Voltage	V <sub>DS</sub>	200	V			
Gate-Source Voltage	Vgs	±20	V			
Drain Current-Continuous	I <sub>D</sub>	24	А			
Drain Current-Continuous(T <sub>C</sub> =100°C)	I <sub>D</sub> (100℃)	17	А			
Pulsed Drain Current	I <sub>DM</sub>	100	А			
Maximum Power Dissipation	P <sub>D</sub>	150	W			
Single pulse avalanche energy (Note 5)	E <sub>AS</sub>	250	mJ			
Operating Junction and Storage Temperature Range	$T_{J}, T_{STG}$	-55 To 175	$^{\circ}$			

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#### **Thermal Characteristic**

# **Electrical Characteristics (TA=25** <sup>°</sup>C unless otherwise noted)

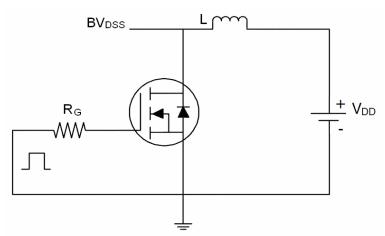
Parameter	Symbol	Symbol Condition		Тур	Max	Unit
Off Characteristics			•			
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250μA	200	220	-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =200V,V <sub>GS</sub> =0V	-	-	1	μA
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V,V <sub>DS</sub> =0V	-	-	±100	nA
On Characteristics (Note 3)	<u>.</u>		•			
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> ,I <sub>D</sub> =250μA	2.5	3.2	4	V
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =15A	-	63	80	mΩ
Forward Transconductance	<b>g</b> FS	V <sub>DS</sub> =50V,I <sub>D</sub> =15A	30	-	-	S
Dynamic Characteristics (Note4)	<u>.</u>		•			
Input Capacitance	C <sub>lss</sub>	\/ -25\/\/ -0\/		4200		PF
Output Capacitance	Coss	$V_{DS}$ =25V, $V_{GS}$ =0V, F=1.0MHz		163		PF
Reverse Transfer Capacitance	C <sub>rss</sub>	F=1.0WID2		75		PF
Switching Characteristics (Note 4)	<u>.</u>		•			
Turn-on Delay Time	t <sub>d(on)</sub>		-	10	-	nS
Turn-on Rise Time	t <sub>r</sub>	V <sub>DD</sub> =100V,I <sub>D</sub> =15A	-	18	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GS}$ =10 $V$ , $R_{GEN}$ =2.5 $\Omega$	-	22	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	5	-	nS
Total Gate Charge	Qg	\/ -400\/   -454		60		nC
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS}$ =100V, $I_{D}$ =15A, $V_{GS}$ =10V		19		nC
Gate-Drain Charge	Q <sub>gd</sub>	V <sub>GS</sub> -10V		17		nC
Drain-Source Diode Characteristics						
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =11A	-	-	1.2	V
Diode Forward Current (Note 2)	Is	-	-	-	24	Α
Reverse Recovery Time	t <sub>rr</sub>	TJ = 25°C, IF = 15A	-	90	-	nS
Reverse Recovery Charge	Qrr	di/dt = 100A/μs(Note3)	-	300	-	nC
Forward Turn-On Time	t <sub>on</sub>	Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD)				

## Notes:

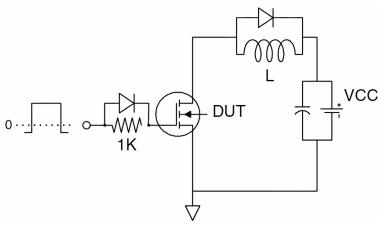
- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- 3. Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.
- 4. Guaranteed by design, not subject to production

# **Test circuit**

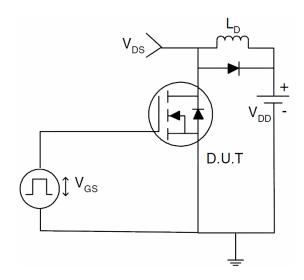
# 1) E<sub>AS</sub> test Circuits



# 2) Gate charge test Circuit:

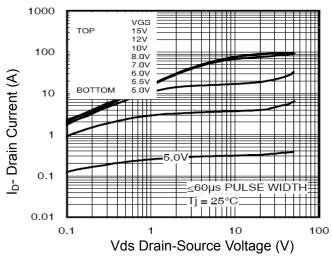


# 3) Switch Time Test Circuit:

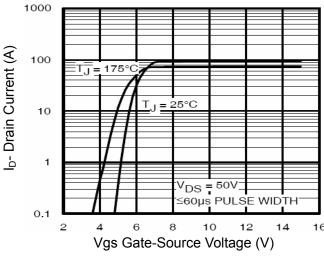


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# TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS (Curves)



**Figure 1 Output Characteristics** 



**Figure 2 Transfer Characteristics** 

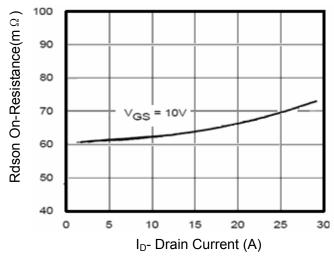


Figure 3 Rdson- Drain Current

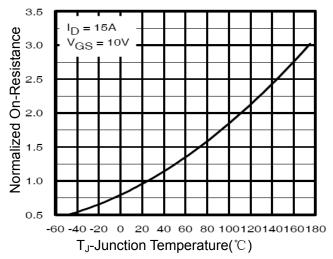


Figure 4 Rdson-JunctionTemperature

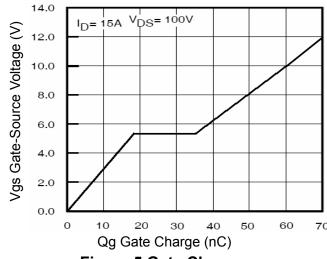


Figure 5 Gate Charge

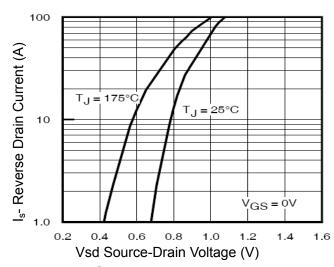


Figure 6 Source- Drain Diode Forward

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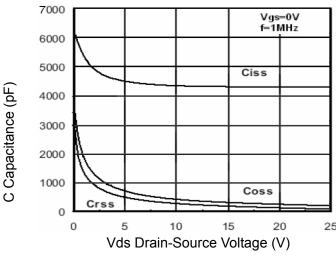


Figure 7 Capacitance vs Vds

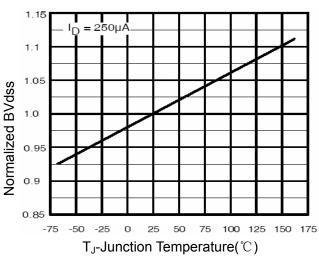


Figure 9 BV<sub>DSS</sub> vs Junction Temperature

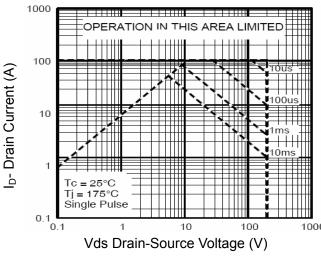


Figure 8 Safe Operation Area

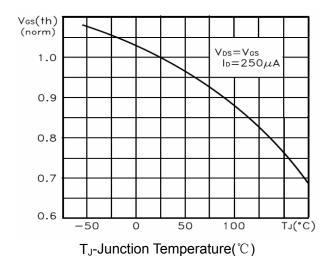


Figure 10 V<sub>GS(th)</sub> vs Junction Temperatur

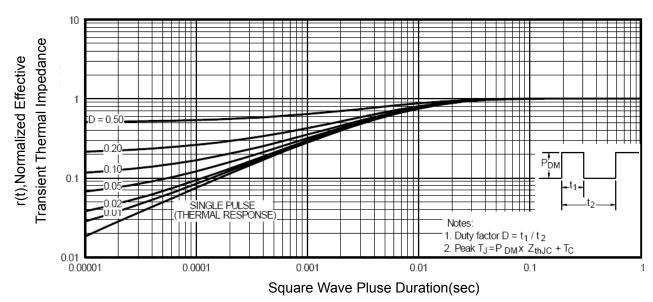
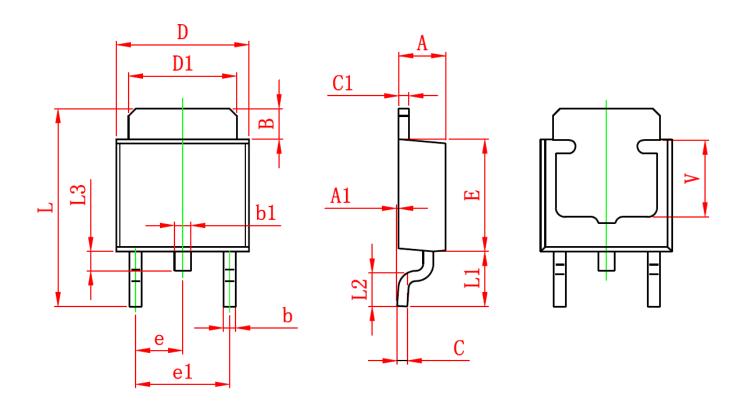


Figure 11 Normalized Maximum Transient Thermal Impedance

# **TO-252-2L Package Information**



Symbol	Dimensions	In Millimeters	Dimensions In Inches		
	Min	Max	Min	Max	
Α	2.200	2.400	0.087	0.094	
A1	1.050	1.350	0.042	0.054	
В	1.350	1.650	0.053	0.065	
b	0.500	0.700	0.020	0.028	
b1	0.700	0.900	0.028	0.035	
С	0.430	0.580	0.017	0.023	
c1	0.430	0.580	0.017	0.023	
D	6.350	6.650	0.250	0.262	
D1	5.200	5.400	0.205	0.213	
E	5.400	5.700	0.213	0.224	
е	2.300	) TYP	0.091 TYP		
e1	4.500	4.700	0.177	0.185	
L	7.500	7.900	0.295	0.311	

Pb Free Product

NCE0224K

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